

1N4148WS

SMALL SIGNAL SWITCHING DIODES

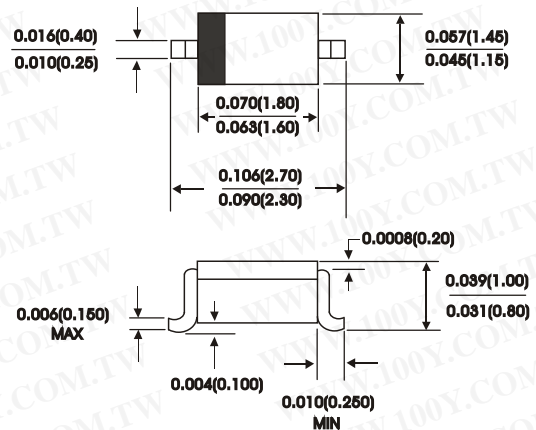
SOD-323

FEATURES:

- Silicon epitaxial planar diode
- Fast switching diodes
- This diodes is also available in other case style including:
 the DO-25 case with the type designation 1N4148, the
 Mini-MELF case with the type designation LL4148, the
 SOD-123 case with the type designation 1N4148W

MECHANICAL DATA

Case: SOD-323 Plastic case
 Weight: Approx. 0.02gram



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temp. unless otherwise specified.

Single phase, half sine wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20 %.

Characteristic	Symbol	1N4148WS	Units
Maximum peak reverse voltage	V_{RM}	100	Volts
Maximum reverse voltage	V_R	75	Volts
Average rectified current .half wave rectification with Resistive load at $T_a=25^\circ C$ And $F \geq 50HZ$	$I_{O(AV)}$	0.15 ¹⁾	Amps
Peak forward surge current, <1S single half sine-wave auperimposed on ratedload $T_a=25^\circ C$	I_{FSM}	0.35	Amps
Power dissipation at $T_a=25^\circ C$	P_{tot}	200 ¹⁾	mW
Maximum instantaneous forward voltage drop per leg at 0.01A	V_F	1.0	Volts
Maximun Voltage rise when switching ON tested with 50mApluse $t=0.1_s$, Rise time <30_s , $f=5$ to 100 KHZ	V_{fr}	2.5	Volts
Maximun leakage current At $V_R=20V$ At $V_R=75V$ At $V_R=20V T_a=150^\circ C$	I_R	25 5 50	nA uA uA
Maximum Reverse recovery time (Note 1)	TRR	4	ns
Maximun Junction capacitance $V_R=V_F=0V$	C_{tot}	4	PF
Maximun Thermal resistance junction to ambient	$R_{th JA}$	650 ¹⁾	K /W
MINMUN rectification efficiency at $f=100MHZ$, $V_{RF}=2V$	η	045	
Operating temperature range	T_J	150	°C
storage temperature range	T_{stg}	-55 to +150	°C

NOTES:

(1)Reverse recovery condition $I_F=0.01A$, $I_R=0.001A$, $V_R=6V$, $R_L=100$

1):Valid provided that electrodes are kept at ambient temperature

RATINGS AND CHARACTERISTIC CURVES 1N4148WS

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

FIG 1-FORWARD CHARACTERISTICS

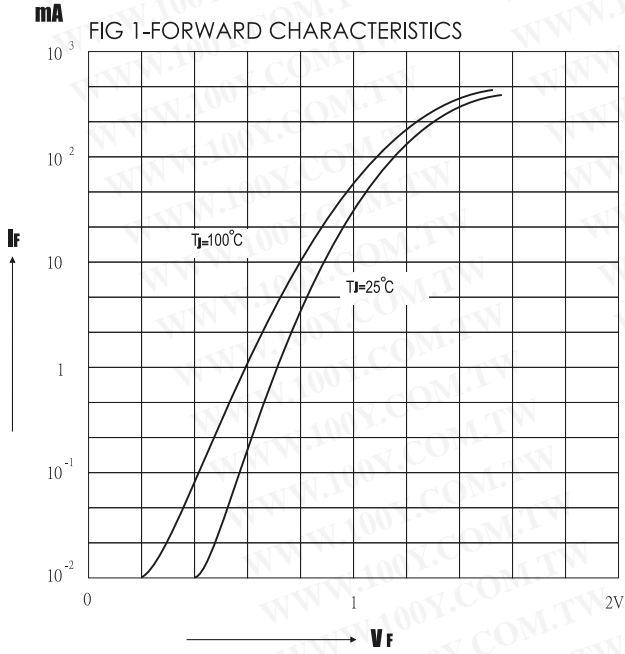


FIG 2: DYNAMIC FORWARD RESISTANCE VERSUS FORWARD CURRENT

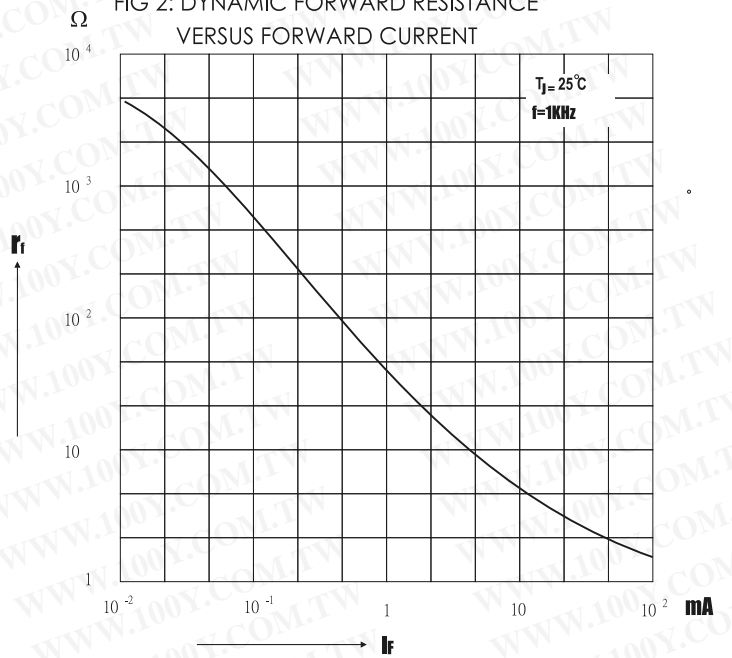


FIG 3-ADMISSIBLE POWER DISSIPATION VERSUS AMBIENT TEMPERATURE

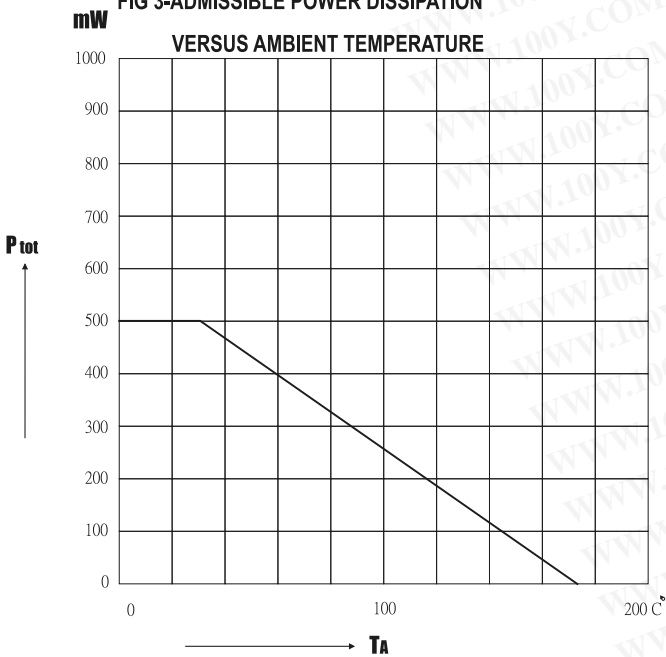
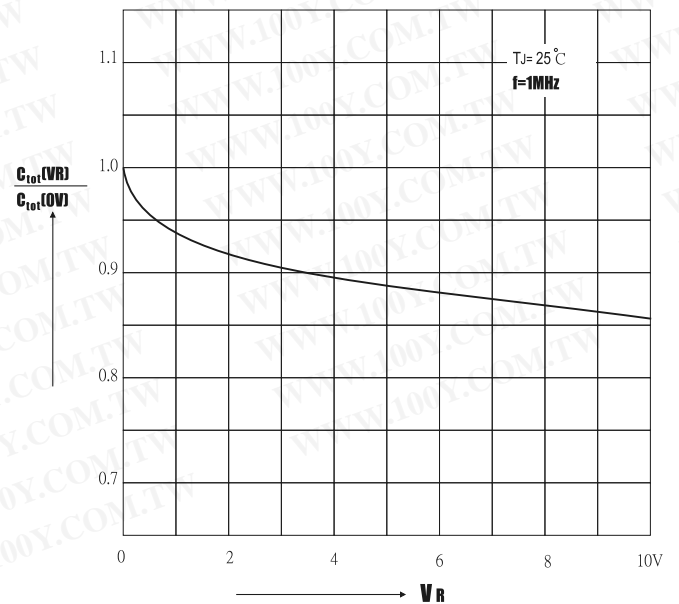


FIG. 4-RELATIVE CAPACITANCE VERSUS REVERS VOLTAGE



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FIG.5 RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

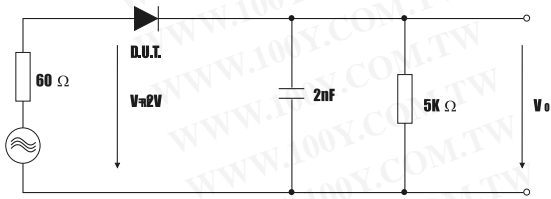


FIG 6: LEAKAGE CURRENT VERSUS JUNCTION TEMPERATURE

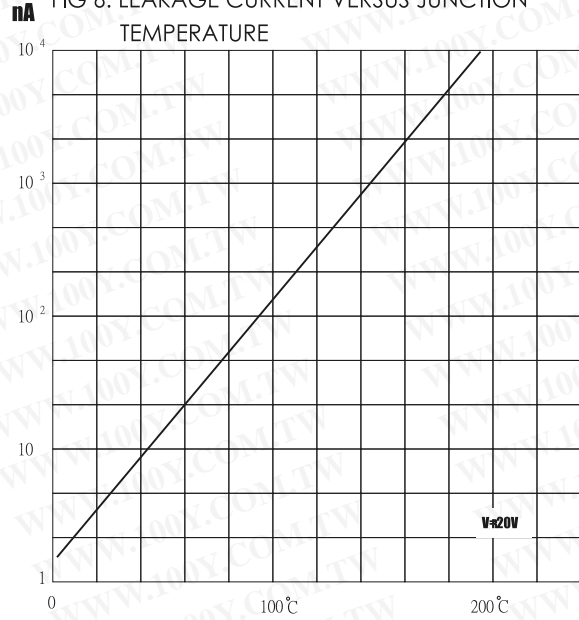


FIG 7: ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION

